NSN 5961-01-341-9621

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-341-9621 **Inclosure Material:** Glass **Overall Length:** 0.200 inches **Terminal Length:** 1.000 inches **Overall Diameter:** 0.090 inches **Function For Which Designed:** Rectifier **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 270.0 nonrepetitive peak reverse voltage and 225.0 working peak reverse voltage **Current Rating Per Characteristic:** 5.00 amperes forward current, average preset **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius ambient air **Test Data Document:** 73030-5r4810-023 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 2 uninsulated wire lead **Specification Data:** 81349-mil-s-19500/240 government specification Shelf Life: N/a **Unit Of Measure: Demilitarization:** No